

Government College of Engineering, Amravati

(An Autonomous Institute of Government of Maharashtra)

Fourth Semester B. Tech.
(Electronics and Telecommunication)

Class Test-II

Sub Code: ETU 402 (Analog Circuit)

Marks: 15

Time: 1 hour

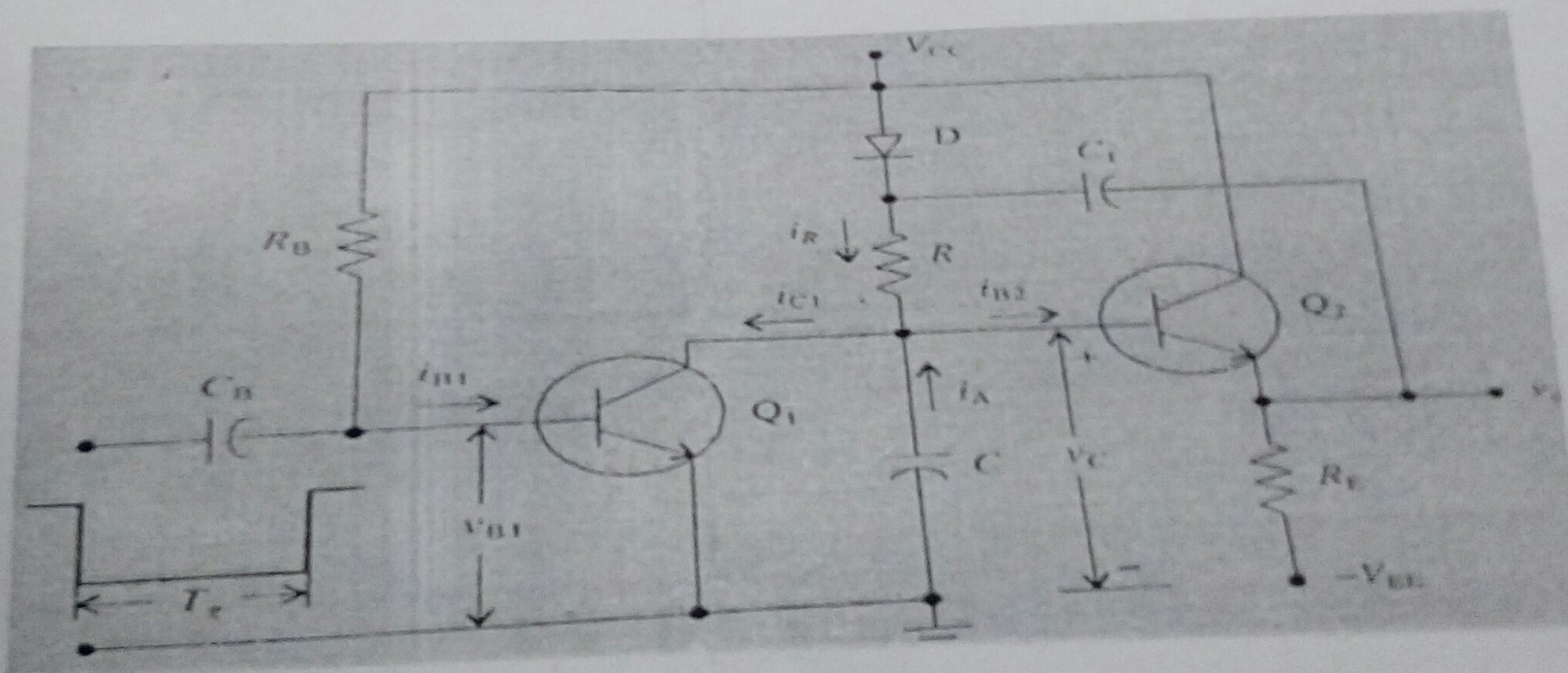
Solve Any 3

Q.1 Derive the relationship between sweep speed error, transmission error, displacement error for any exponential sweep circuit, using proper circuit diagram. (05)

Q.2 Draw a UJT sweep circuit having the following parameters, $V_{BB}=20V$, $V_{DD}=50V$, $R=5k\Omega$, $R_{B1}=R_{B2}=0\Omega$, $C=0.01\mu F$, also calculate (a) Amplitude of sweep signal, (b) Slope and displacement error (c) Duration of sweep (d) Recovery time. (05)

Q.3 The following specifications are given for the dual input, balanced-output differential amplifier having $R_C = 2.2 k\Omega$, $R_{S1} = R_{S2} = 50\Omega$, $+V_{CC} = 10V$, $-V_{EE} = -10V$, $\beta_{dc} = 100$ and $V_{BE1} = V_{BE2} = 0.715V$. Determine the operating points (I_{CQ} and V_{CEQ}) of the two transistors. (05)

Q.4 In the transistor bootstrap circuit as shown in figure below have $V_{CC}=25V$, $V_{EE}=-15V$, $R=10k\Omega$, $R_E=15k\Omega$, $R_B=150k\Omega$, $C=0.05 \mu F$ and $C_1=100 \mu F$. The gating waveform has a duration, $T_g=300 \mu s$. The transistor parameters are $h_{ie}=1.1 k\Omega$, $h_{re}=0.25\Omega$, $h_{fe}=50$, $h_{oe}=1/40$. (a) Draw the waveform of i_{C1} and V_O , labeling all current and voltage levels. (b) What is the slope error of the sweep? (c) What is the sweep speed and the maximum value of the speed and maximum value of the sweep voltage? (d) What is the retrace time T_r for C to discharge completely? (e) Calculate the recovery time T_1 for C_1 to recharge completely. (05)



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Electronics and Telecommunication Department

Class Test: 2
Subject: ETU 402
Solve any three

Max. Marks: 15

Date: 13/03/2015

All questions carry equal marks

- 1) Draw and explain in detail each component of the high frequency hybrid- π model for BJT. Also derive the expression for r_π and g_m and give the relation between r_π , g_m and β .
- 2) For a single stage RC-coupled amplifier, derive the expression for Miller Capacitance and explain its effect on the high frequency response of the amplifier.
- 3) For a CE-amplifier with the following parameters $R_1 = 51.2 \text{ k}\Omega$, $R_2 = 9.6 \text{ k}\Omega$, $R_C = 2 \text{ k}\Omega$, $R_E = 0.4 \text{ k}\Omega$, $R_S = 0.1 \text{ k}\Omega$, $C_{in} = 1 \mu\text{F}$, $C_E = 0$, $C_{out} = 0$ and $V_{CC} = 10 \text{ V}$. The transistor parameters are $V_{BE(on)} = 0.7 \text{ V}$, $\beta = 100$ and $V_A = \infty$. Calculate the lower cut-off frequency due to C_{in} and the maximum gain.
- 4) For a CE-amplifier with C_{in} , C_{out} and C_E , $R_1 = 200 \text{ k}\Omega$, $R_2 = 220 \text{ k}\Omega$, $R_C = 2.2 \text{ k}\Omega$, $R_L = 4.7 \text{ k}\Omega$, $R_E = 1 \text{ k}\Omega$, $R_S = 100 \text{ k}\Omega$ and $V_{CC} = 5 \text{ V}$. The transistor parameters are $\beta_0 = 100$, $V_{BE(on)} = 0.7 \text{ V}$, $V_A = \infty$, $C_\pi = 10 \text{ pF}$ and $C_\mu = 2 \text{ pF}$. Calculate (a) The Miller Capacitance, and (b) the 3dB frequency.
- 5) (a) Derive the expression for $\beta(f)$ and give the expression for f_β .
(b) Calculate f_β and f_T if, $\beta_0 = 150$, $C_\pi = 4 \text{ pF}$, $C_\mu = 0.5 \text{ pF}$ and $I_{C(dc)} = 1 \text{ mA}$.